



**KERSEMI**

**HIGH VOLTAGE POWER SCHOTTKY RECTIFIER**

**MBR20H100C**

**General Description**

High voltage dual Schottky rectifier suited for switch mode power supplies and other power converters. This device is intended for use in medium voltage operation, and particularly, in high frequency circuits where low switching losses and low noise are required.

MBR20H100C is available in TO-220F-3, TO-220-3 and TO-220-3 (2) packages.

**Features**

- Low Forward Voltage: 0.64V @ 125°C
- High Surge Capacity
- 175°C Operating Junction Temperature
- 20A Total (10A Each Diode Leg)
- Guard-ring for Stress Protection
- Pb-free Package

**Applications**

- Power Supply Output Rectification
- Power Management
- Instrumentation

**Main Product Characteristics**

$I_F (AV)$	2×10A
$V_{RRM}$	100V
$T_J$	175°C
$V_F (max)$	0.64V

**Mechanical Characteristics**

- Case: Epoxy, Molded
- Epoxy Meets UL 94V-0 @ 0.125in.
- Weight (Approximately):  
2Grams (TO-220-3, TO-220-3 (2) and TO-220F-3)
- Finish: All External Surfaces Corrosion Resistant and Terminal
- Leads are Readily Solderable
- Lead Temperature for Soldering Purposes:  
260°C Maximum for 10 Seconds

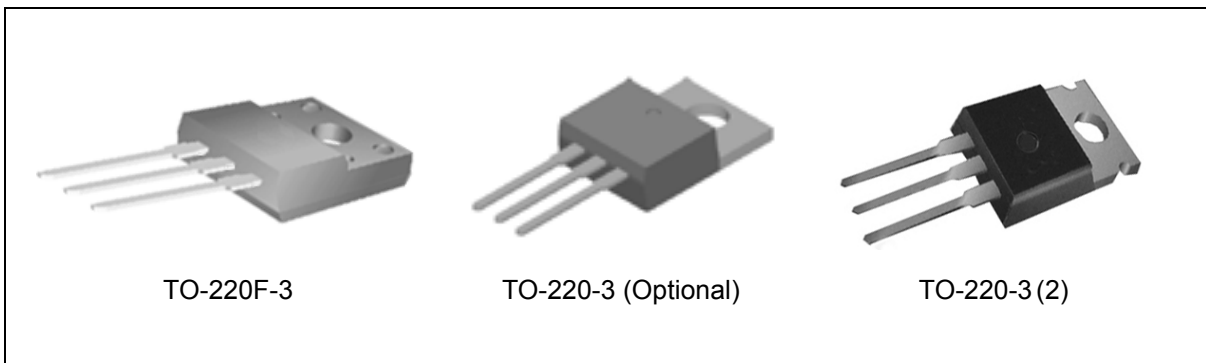


Figure 1. Package Types of MBR20H100C



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**Pin Configuration**

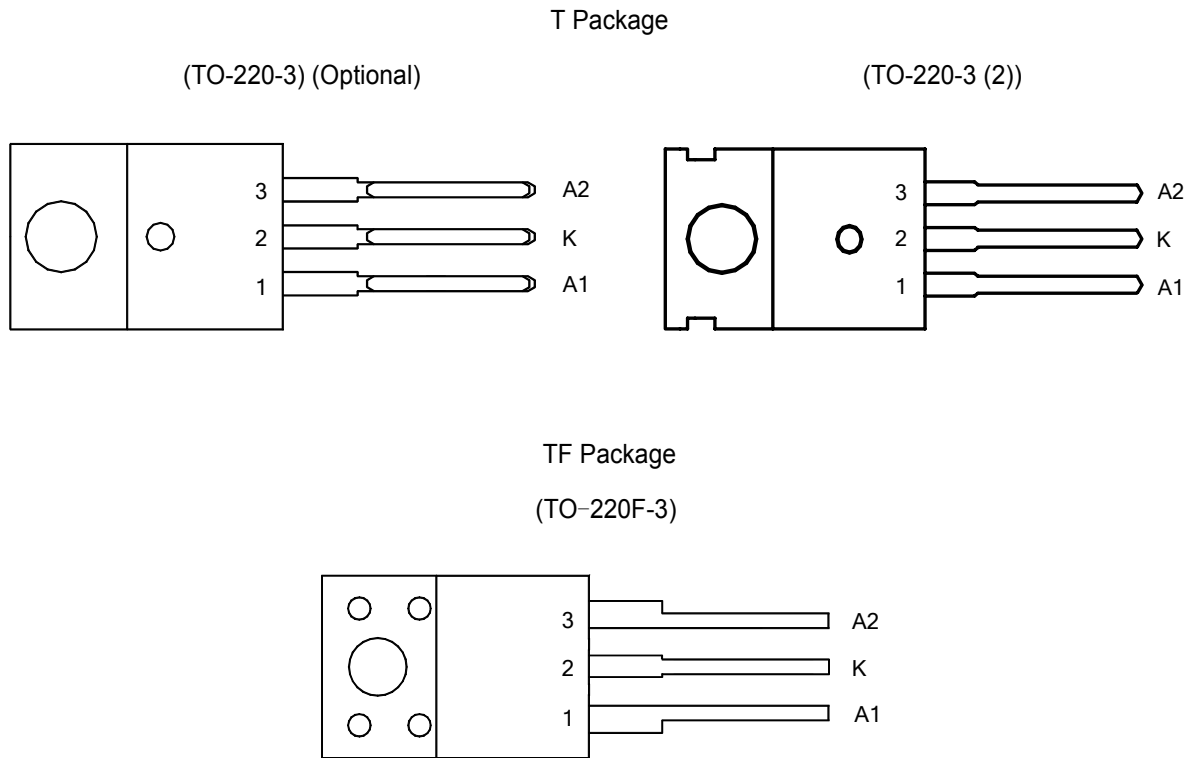


Figure 2. Pin Configuration of MBR20H100C (Top View)

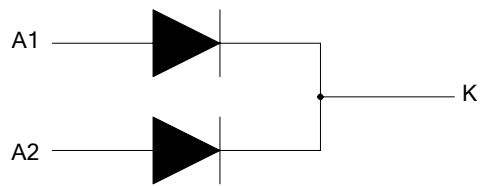


Figure 3. Internal Structure of MBR20H100C

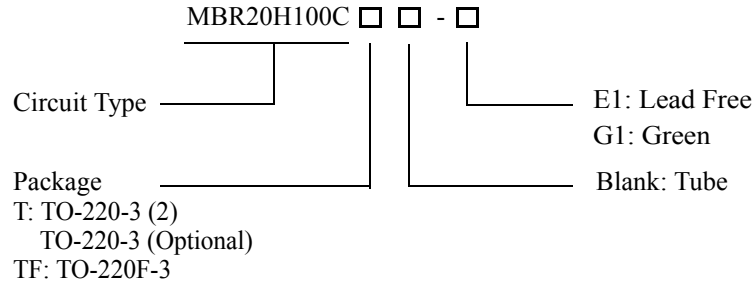


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**Ordering Information**



Package	Part Number		Marking ID		Packing Type
	Lead Free	Green	Lead Free	Green	
TO-220-3 (2)	MBR20H100CT-E1	MBR20H100CT-G1	MBR20H100CT-E1	MBR20H100CT-G1	Tube
TO-220F-3	MBR20H100CTF-E1	MBR20H100CTF-G1	MBR20H100CTF-E1	MBR20H100CTF-G1	Tube



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**Absolute Maximum Ratings (Each Diode Leg) (Note 1)**

Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	100	V
Average Rectified Forward Current (Rated $V_R$ ) $T_C=162^{\circ}C$	$I_{F(AV)}$	10	A
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20kHz) $T_C=160^{\circ}C$	$I_{FRM}$	20	A
Non Repetitive Peak Surge Current (Surge Applied at Rated load Conditions Half Wave, Single Phase, 60Hz)	$I_{FSM}$	250	A
Operating Junction Temperature (Note 2)	$T_J$	175	$^{\circ}C$
Storage Temperature Range	$T_{STG}$	-65 to 175	$^{\circ}C$
Voltage Rate of Change (Rated $V_R$ )	dv/dt	10000	V/ $\mu s$
ESD (Machine Model=C)		>400	V
ESD (Human Body Model=3B)		>8000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: The heat generated must be less than the thermal conductivity from Junction to Ambient:  $dP_D/dT_J < 1/\theta_{JA}$ .

**Thermal Characteristics**

Parameter	Symbol	Condition	Value	Unit
Maximum Thermal Resistance	$\theta_{JC}$	Junction to Case	TO-220-3/ TO-220-3 (2)	2.0
			TO-220F-3	2.5
	$\theta_{JA}$	Junction to Ambient	TO-220-3/ TO-220-3 (2)	60



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**Electrical Characteristics (Each Diode Leg)**

Parameter	Symbol	Condition	Value	Unit
Maximum Instantaneous Forward Voltage Drop (Note 3)	$V_F$	$I_F=10A, T_C=25^{\circ}C$	0.77	V
		$I_F=10A, T_C=125^{\circ}C$	0.64	
		$I_F=20A, T_C=25^{\circ}C$	0.88	
		$I_F=20A, T_C=125^{\circ}C$	0.73	
Maximum Instantaneous Reverse Current (Note 3)	$I_R$	Rated DC Voltage, $T_C=125^{\circ}C$	6.0	mA
		Rated DC Voltage, $T_C=25^{\circ}C$	0.0045	

Note 3: Pulse Test: Pulse Width=300 $\mu$ s, Duty Cycle $\leq$ 2.0%.



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**Typical Performance Characteristics**

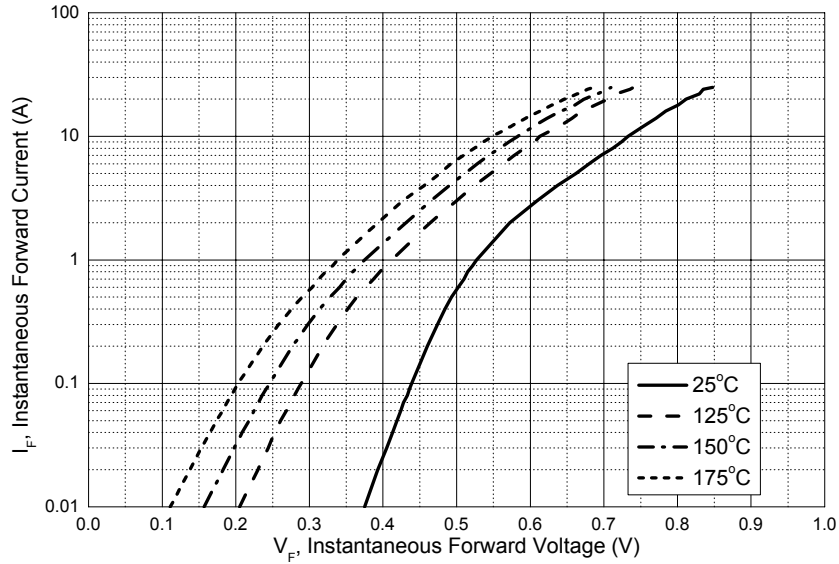


Figure 4. Typical Forward Voltage

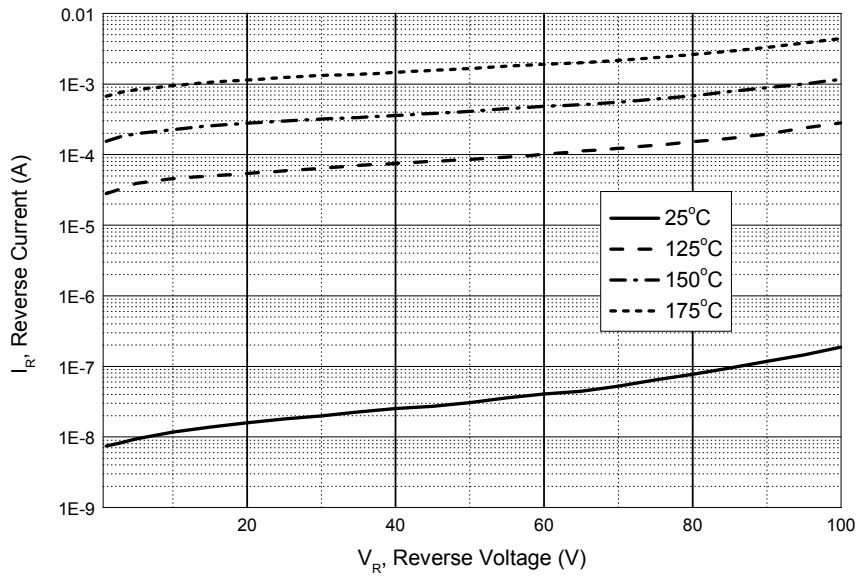


Figure 5. Typical Reverse Current



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**Typical Performance Characteristics (Continued)**

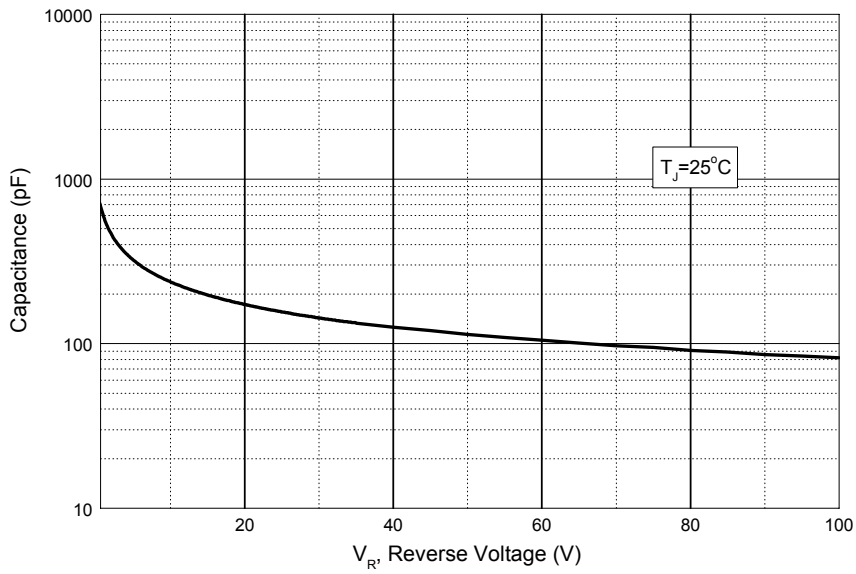


Figure 6. Capacitance vs.  $V_R$ , Reverse Voltage

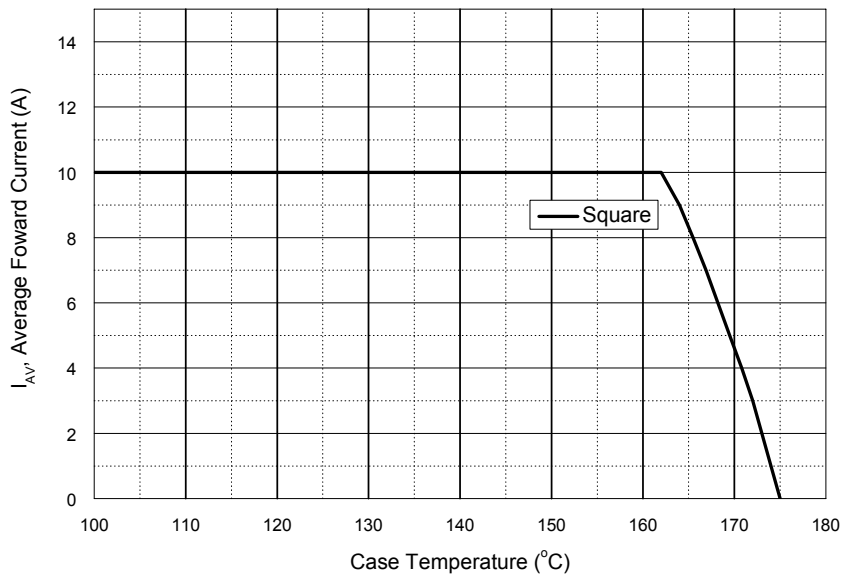


Figure 7. Average Forward Current vs. Case Temperature (Square, Each Diode)







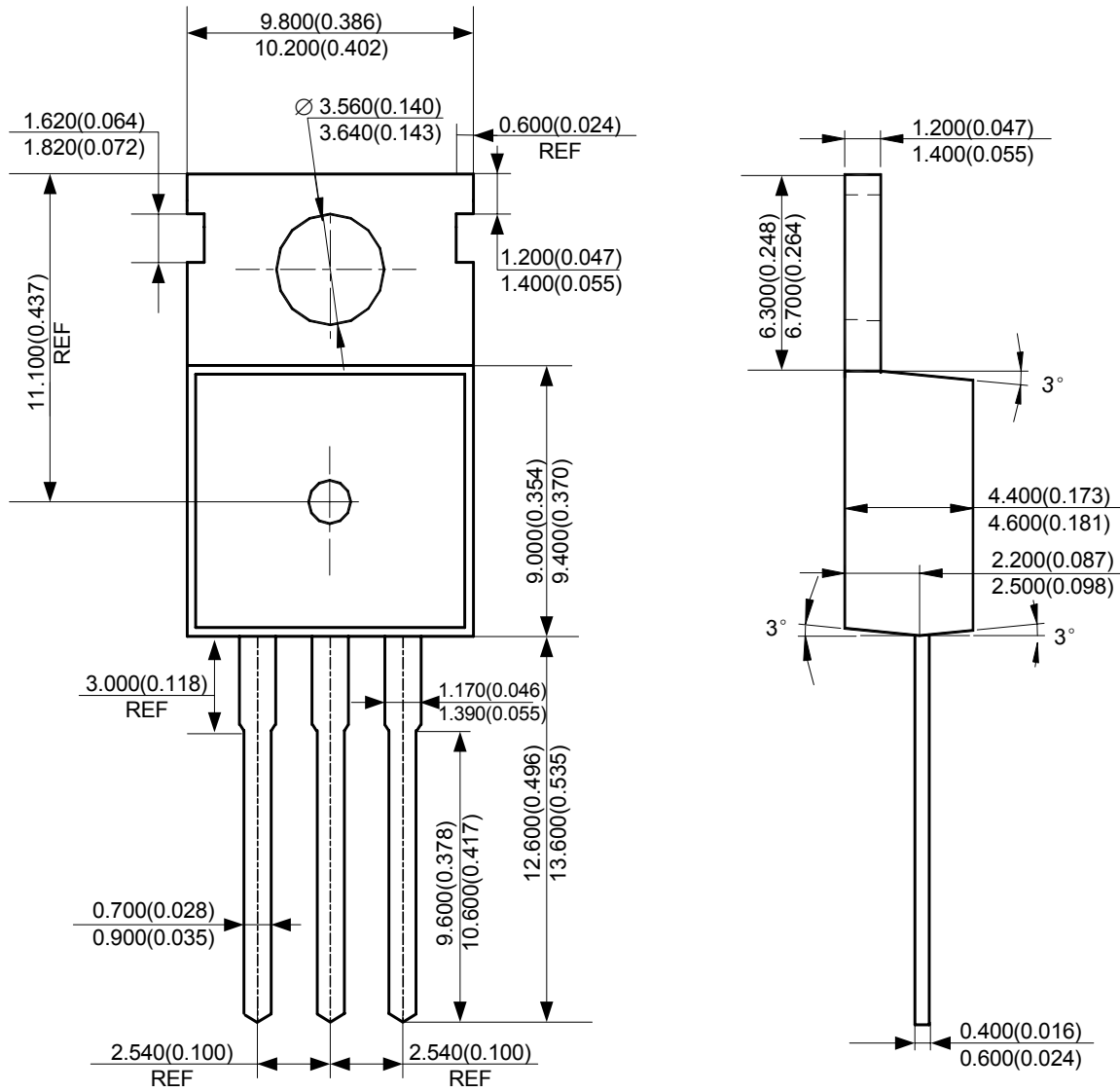
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**TO-220-3 (2)**

**Unit: mm(inch)**





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**TO-220F-3**

**Unit: mm(inch)**

